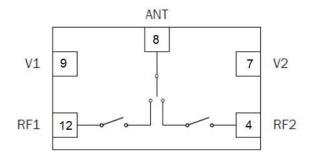


RFSW6023

2.5V to 5V, 10W SPDT Switch 150MHz to 5000MHz

The RFSW6023 is a high power single-pole double-throw (SPDT) switch designed for high performance wireless applications. This wideband switch has been designed for use from 50MHz to 5000MHz, where extremely high linearity, high isolation, low insertion loss, and small package size are required. Switching for the RFSW6023 controlled via two control voltage inputs. The RFSW6023 is manufactured in a pHEMT GaAs process and packaged in a 12-pin, 3mm x 3mm, quad-flat (QFN) plastic package.



Functional Block Diagram

Ordering Information

RFSW6023SQ	Sample bag with 25 pieces
RFSW6023SR	7" Reel with 100 pieces
RFSW6023TR7	7" Reel with 2500 pieces
RFSW6023PCK-410	150MHz to 5000MHz PCBA with 5-piece sample bag





Package: QFN, 12-pin, 3.0mm x 3.0mm

Features

- Single Voltage: 2.5V to 5.0V
- 40dBm P0.1dB
- 25dB Isolation at 2GHz
- High Linearity

Applications

- Wireless Infrastructure
- ISM Band Transmitter
- WiMax
- WLAN



Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage (RF Applied)	-0.5 to +5.0	V
Supply Voltage (No RF Applied)	-0.5 to +5.0	V
DC Supply Current	10	mA
Input Peak Envelope Power	+40*	dBm
Max Input Power, OFDM Modulated, 3:1 Load VSWR	+36	dBm
Max Input 3:1 VSWR	36	dBm
Operating Ambient Temperature	-40 to +85	°C
Junction Temperature	150	°C
Storage Temperature	-40 to +150	°C
Moisture Sensitivity Level	MSL1	

*Maximum input power with a 50 Ω load.

Nominal Operating Parameters





RFMD Green: RoHS status based on EU Directive 2011/65/EU (at time of this document revision), halogen free per IEC 61249-2-21, < 1000pm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

Deremeter	Specification		Specification		Unit	Condition
Parameter	Min	Тур	Max	Unit	Condition	
Low Band Performance					Temp = 25°C, VC = 3V, unless otherwise noted	
Frequency Range	100		2000	MHz		
Insertion Loss		0.4	0.7	dB		
Input P0.1dB		40		dBm		
Input Return Loss		20		dB		
Isolation		25		dB	2000MHz	
Harmonics (2 nd , 3 rd)		80		dBc	At P _{OUT} = 30dBM, 880MHz	
Input IP3		59		dBm	150MHz, 23dBm/tone	
High Band Performance					Temp = 25°C, VC = 3V, unless otherwise noted	
Frequency Range	2000		5000	MHz		
Insertion Loss		0.6	0.8	dB		
Input P0.1dB		40		dBm		
Input Return Loss		15		dB		
Isolation		26		dB	3800MHz	
Harmonics (2 nd , 3 rd)		80		dBc	At P _{OUT} = 30dBM, 2140MHz	
Input IP3		59		dBm	2000MHz, 23dBm/tone	
Control Voltage						
Control Voltage High	2.5	3	5	V		
Control Voltage Low			0.2	V		
Control Current		5		μA		

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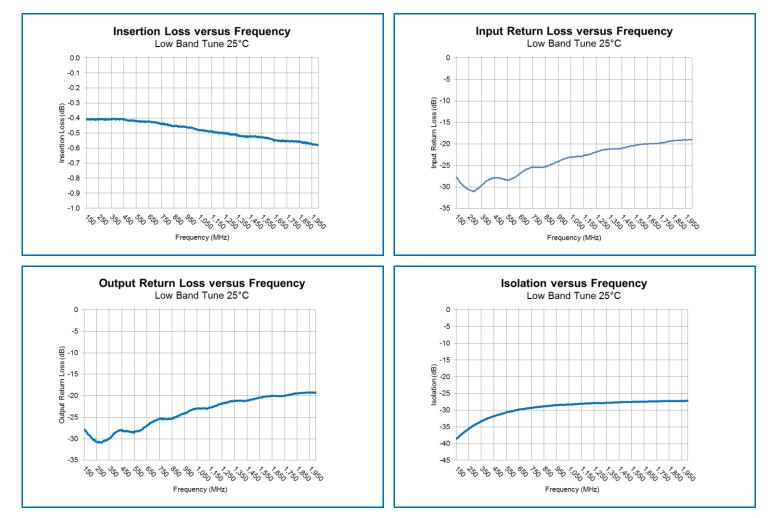
Parameter	Specification			Unit	Condition
	Min	Тур	Мах	Unit	Condition
Generic Performance					
Switching Speed High		300	500	ns	50% CTL to 90/10% RF
Switching Speed Low		100	300	ns	90/10% RF to 10/90% RF
ESD					
Human Body Model	250			V	EIA/JESD22-114A RF pins
	500			V	EIA/JESD22-114A DC pins
Charge Device Model	1000			V	JESD22-C101C all pins

Control Truth Table

Switch	Status	Logic Control			
RF1 to RFC	RF2 to RFC	VRF1	VRF2		
On	Off	High	Low		
Off	On	Low	High		



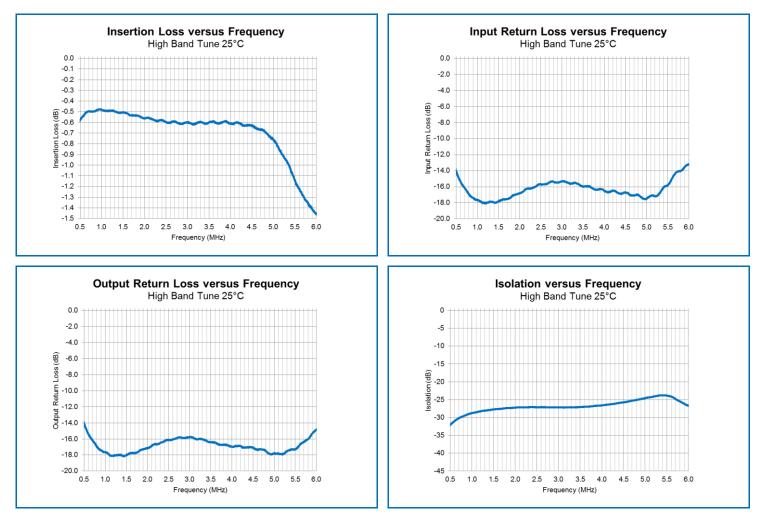
Typical Performance: Low Band



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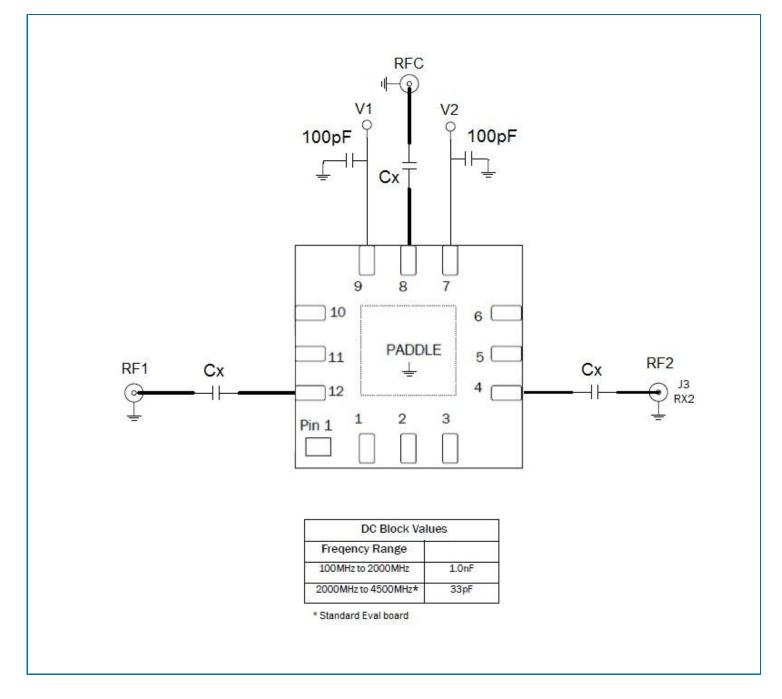
Typical Performance: High Band



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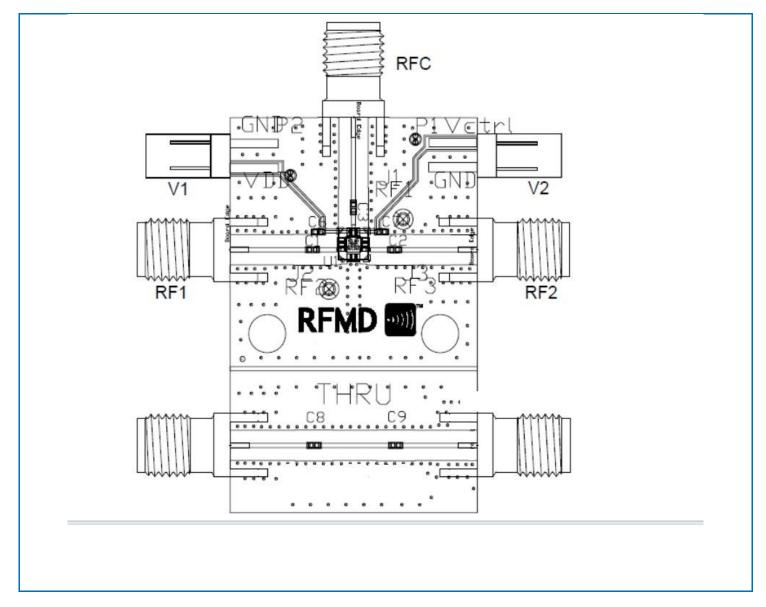
Evaluation Board Schematic



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Evaluation Board Assembly Drawing



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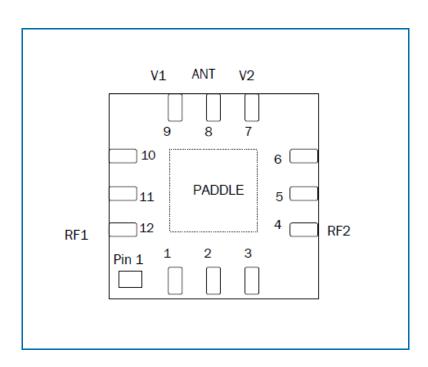
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Pin Names and Descriptions

Pin	Name	Description					
1	NC	No connect					
2	NC	No connect					
3	NC	No connect					
4	RF2	RF Port 2, DC block required					
5	NC	No connect					
6	NC	No connect					
7	V2	V2 Logic Control Voltage					
8	ANT RF	RF Common Port, DC block required					
9	V1	V1 Logic Control Voltage					
10	NC	No connect					
11	NC	No connect					
12	RF1	RF Port 1, DC block required					
	Paddle	Ground					

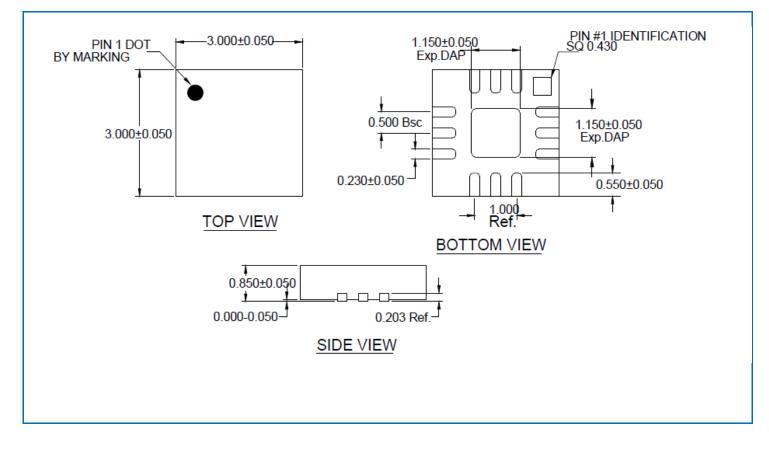
Pin Layout



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Package Outline Drawing (Dimensions in millimeters)





Branding Diagram

